Amplifier Transistors NPN Silicon

COLLECTOR

2
BASE

3
EMITTER

MAXIMUM RATINGS

Rating	Symbol	BC 546	BC 547	BC 548	Unit
Collector-Emitter Voltage	VCEO	65	45	30	Vdc
Collector-Base Voltage	V _{СВО}	80	50	30	Vdc
Emitter-Base Voltage	VEBO	6.0		Vdc	
Collector Current — Continuous	IC	100		mAdc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12		Watt mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150		°C	

BC546, B BC547, A, B, C BC548, A, B, C



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

					1	
Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I _C = 1.0 mA, I _B = 0)	BC546 BC547 BC548	V(BR)CEO	65 45 30	_ _ _	_ _ _	V
Collector-Base Breakdown Voltage (I _C = 100 μAdc)	BC546 BC547 BC548	V(BR)CBO	80 50 30	_ _ _	_ _ _	V
Emitter-Base Breakdown Voltage (IE = 10 μ A, IC = 0)	BC546 BC547 BC548	V(BR)EBO	6.0 6.0 6.0	_ _ _	_ _ _	V
Collector Cutoff Current (VCE = 70 V, VBE = 0) (VCE = 50 V, VBE = 0) (VCE = 35 V, VBE = 0) (VCE = 30 V, TA = 125°C)	BC546 BC547 BC548 BC546/547/548	ICES	_ _ _ _	0.2 0.2 0.2 —	15 15 15 4.0	nA μA

BC546, B BC547, A, B, C BC548, A, B, C

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS						
DC Current Gain (I _C = 10 μ A, V _{CE} = 5.0 V)	BC547A/548A BC546B/547B/548B BC548C	hFE	_ _ _	90 150 270	_ _ _	_
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC546 BC547 <mark>BC548</mark> BC547A/548A BC546B/547B/548B BC547C/BC548C		110 110 110 110 110 200 420	— — — 180 290 520	450 800 <mark>800</mark> 220 450 800	
$(I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC547A/548A BC546B/547B/548B BC548C		_ _ _	120 180 300	_ _ _	
Collector-Emitter Saturation Voltage (IC = 10 mA, IB = 0.5 mA) (IC = 100 mA, IB = 5.0 mA) (IC = 10 mA, IB = See Note 1)		VCE(sat)	<u>-</u> -	0.09 0.2 0.3	0.25 0.6 0.6	V
Base-Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.5 mA)		V _{BE} (sat)	_	0.7	_	V
Base–Emitter On Voltage (IC = 2.0 mA, VCE = 5.0 V) (IC = 10 mA, VCE = 5.0 V)		VBE(on)	0.55		<mark>0.7</mark> 0.77	V
SMALL-SIGNAL CHARACTERISTICS		•	•	•		
Current-Gain — Bandwidth Product (I _C = 10 mA, V _{CE} = 5.0 V, f = 100 MHz)	BC546 BC547 BC548	fΤ	150 150 150	300 300 300	_ _ _	MHz
Output Capacitance (V _{CB} = 10 V, I _C = 0, f = 1.0 MHz)		C _{obo}	_	1.7	4.5	pF
Input Capacitance (VEB = 0.5 V, I _C = 0, f = 1.0 MHz)		C _{ibo}	_	10	_	pF
Small–Signal Current Gain (I _C = 2.0 mA, V _{CE} = 5.0 V, f = 1.0 kHz)	BC546 BC547/548 BC547A/548A BC546B/547B/548B BC547C/548C	h _{fe}	125 125 125 125 240 450		500 900 260 500 900	_
Noise Figure (I _C = 0.2 mA, V_{CE} = 5.0 V, R_S = 2 k Ω , f = 1.0 kHz, Δ f = 200 Hz)	BC546 BC547 BC548	NF	_ _ _	2.0 2.0 2.0	10 10 10	dB

Note 1: I_B is value for which I_C = 11 mA at V_{CE} = 1.0 V.

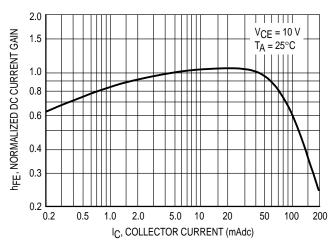


Figure 1. Normalized DC Current Gain

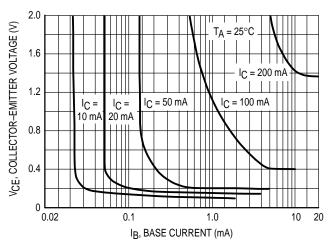


Figure 3. Collector Saturation Region

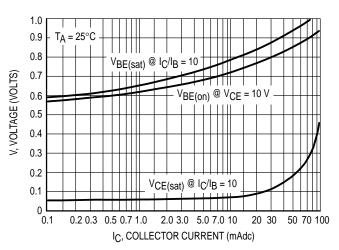


Figure 2. "Saturation" and "On" Voltages

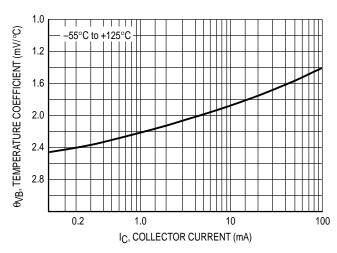


Figure 4. Base-Emitter Temperature Coefficient

BC547/BC548

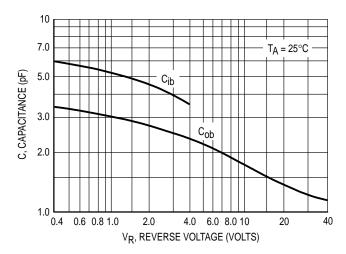


Figure 5. Capacitances

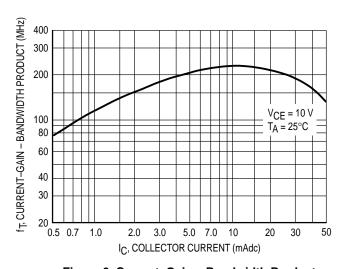


Figure 6. Current-Gain - Bandwidth Product

BC547/BC548

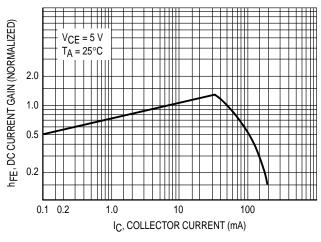


Figure 7. DC Current Gain

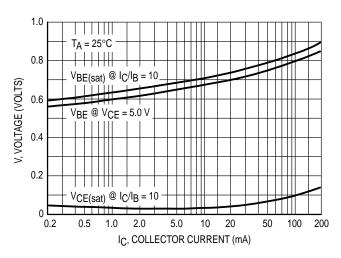


Figure 8. "On" Voltage

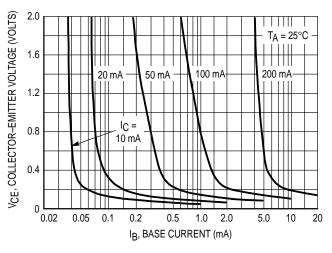


Figure 9. Collector Saturation Region

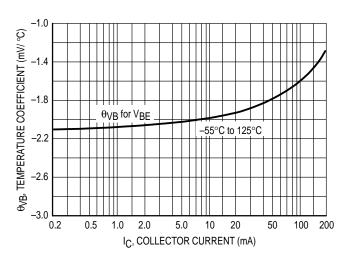


Figure 10. Base-Emitter Temperature Coefficient

BC546

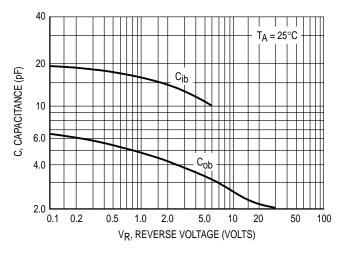


Figure 11. Capacitance

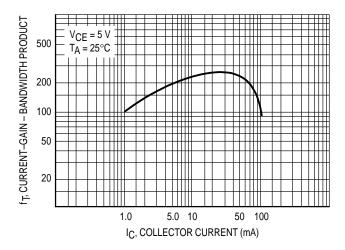
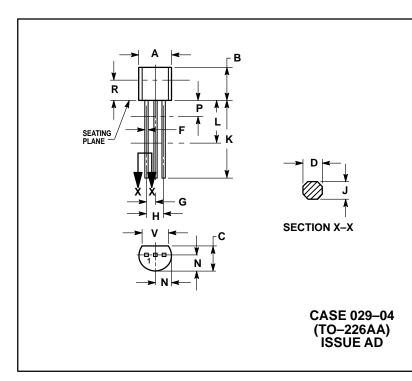


Figure 12. Current-Gain - Bandwidth Product

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION DO AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70	-	
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100	-	2.54	
R	0.115		2.93		
٧	0.135		3.43		

STYLE 17:
PIN 1. COLLECTOR
2. BASE
3. EMITTER

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